

# MBRF20100CTL

REVERSE VOLTAGE - 100 Volts FORWARD CURRENT - 20 Amperes

**ITO-220AB** 

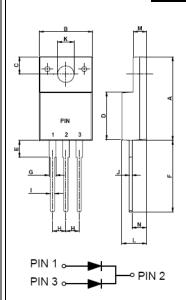
## SCHOTTKY BARRIER RECTIFIERS

#### **FEATURES**

- Metal of silicon rectifier, majority carrier conduction
- Guard ring for transient protection
- Low power loss, high efficiency
- High surge&current capability, low VF
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications

### **MECHANICAL DATA**

- Case: ITO-220AB molded plastic
- Plastic package has UL flammability classification 94V-0
- Terminals: Matte Tin, solderable per MIL-STD-202 Method 208
- Moisture sensitivity: level 1 per J-STD-020D
- · Lead Free Finish, RoHS Compliant
- Polarity: As marked on the body
- Weight: 1.65 grams · Mounting position: Any
- Max. mounting torque = 0.5 N.m (5.1 Kgf-cm)



ITO-220AB				
DIM.	MIN.	MAX.		
Α	15.50 16.50			
В	10.0	10.40		
С	3.00	3.50		
D	9.00	9.30		
E	2.90	3.60		
F	13.46	14.22		
G	1.15	1.70		
Н	2.40	2.70		
I	0.75	1.00		
J	0.45	0.70		
K	3.00Ø	3.30 Ø		
L	4.36	4.77		
M	2.48	2.80		
N	2.50	2.80		
All Dimensions in millimeter				

#### **MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS**

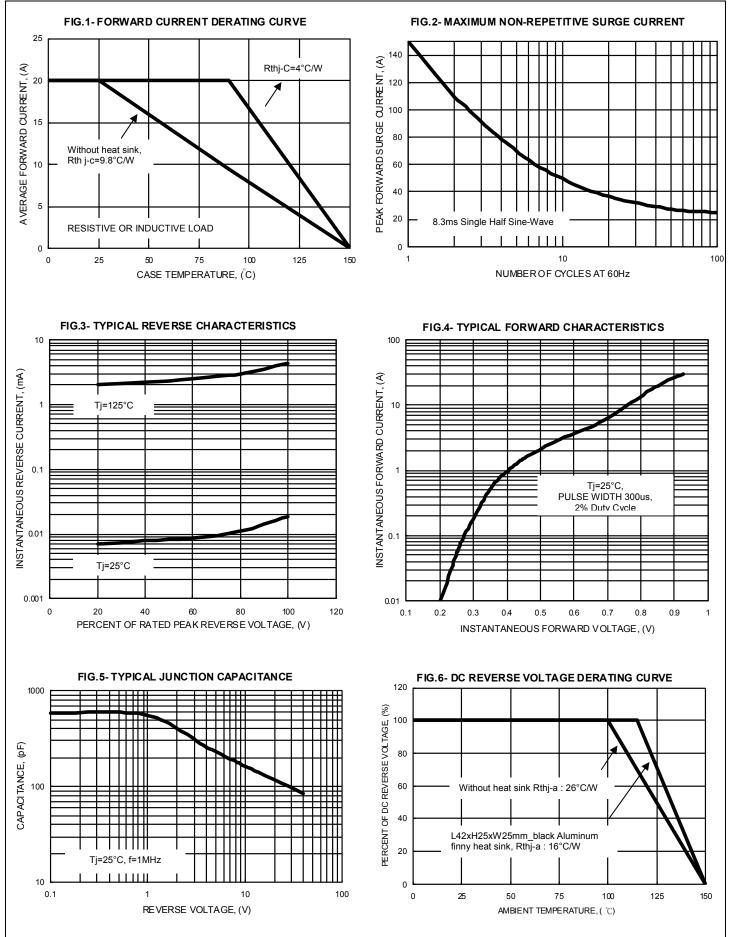
Ratings at 25°C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

PARAMETER	SYMBOL	MBRF20100CTL	UNIT
Maximum Repetitive Peak Reverse Voltage	V <sub>RRM</sub>	100	V
Maximum RMS Voltage	V <sub>RMS</sub>	70	V
Maximum DC Blocking Voltage	V <sub>DC</sub>	100	V
Average Rectified Output Current @Tc=95°C	I <sub>F</sub>	20	А
Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rated load	I <sub>FSM</sub>	150	А
Maximum Forward Voltage IF=10A@ Tj=25°C Note(1) IF=10A@ Tj=125°C	V <sub>F</sub>	0.82 0.75	V
Maximum DC Reverse Current at Rated DC Tj=25°C Blocking Voltage Tj=100°C	IR	0.1 10	mA
Typical Junction Capacitance per element (2)	CJ	250	₽F
Typical thermal resistance Junction to Case (3)	R⊕ <sub>JC</sub>	4.0	°C/W
Operating junction temperature range	TJ	-55 to +150	°C
Storage temperature range	T <sub>STG</sub>	-55 to +150	°C
Note :	•	REV. 1, Oct-2008	3, KTHC64

(1) 300us Pulse Width, 2% Duty Cycle.

- (2) Measured at 1.0MHz and applied reverse voltage of 4.0  $V_{DC}$ .
- (3) Thermal Resistance Junction to Case, device mounted on L250 x W250 x H20 mm \_ Aluminum heat sink,





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